

INFORMATION DISCLOSURE
CITATION IN AN
APPLICATION
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APPLICANT
Arnaud GRISARD et al.

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GROUP

US PATENT DOCUMENTS

[illegible][illegible]

OTHER ART. Involving author, title, date, pertinent tapes, etc.

Christopher B. Ebert, Loren A. Eyres, Martin M. Fejer, James S. Harris, Jr. "MBE growth of antiphase GaAs films using GaAs/Ge/GaAs heteroepitaxy" *Journal of Crystal Growth* 201/202 (1988) 187-193

EXAMINER

DATE CONSIDERED

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.